

DESCRIPTION

The ICPL0600, ICPL0601 and ICPL0611 devices each consist of an infrared emitting diode, optically coupled to a high speed integrated photo detector logic gate with a strobable output.

These devices belong to Isocom Compact Range of Optocouplers.

FEATURES

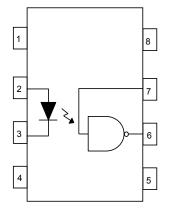
- Half Pitch 1.27mm
- High Speed 10Mbit/s
- 10kV/µs min. Common Mode Transient Immunity (ICPL0611)
- High AC Isolation voltage 3750V_{RMS}
- Guaranteed Performance from -40°C to 85°C
- Wide Operating Temperature Range -40°C to 100°C
- Logic Gate Output
- Pb Free and RoHS Compliant
- Halogen Free
- Safety Approvals Pending

APPLICATIONS

- Line Receivers, Data Communication
- LSTTL to TTL, LSTTL or 5V CMOS
- Data Multiplexing
- Pulse Transformer Replacement
- Switch Mode Power Supplies
- Ground Loop Elimination
- Computer Peripheral Interface

ORDER INFORMATION

 Add T&R after PN for Surface Mount Tape & Reel



- 1. No Connection
- 2. Anode
- 3. Cathode
- 4. No Connection
- 5. Gnd
- 6. Vout
- 7. V_E
- $8. V_{CC}$

A $0.1\mu F$ bypass capacitor must be connected between pins 8 and 5.

ABSOLUTE MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Input Diode

Forward Current	20mA
Reverse Voltage	5V
Power dissipation	40mW

Output

Output Current	50mA
Output Voltage	7.0V
Supply Voltage	7.0V
Enable Input Voltage	5.5V
(maximum 500mV above V _{CC})	
Enable Input Current	5mA
Power Dissination	85m\W

Total Package

Isolation Voltage	$3750V_{RMS}$
Operating Temperature	-40 to 100 °C
Storage Temperature	-55 to 125 °C
Lead Soldering Temperature (10s)	260°C

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Truth Table (Positive Logic)

Input	Enable	Output
Н	Н	L
L	Н	Н
Н	L	Н
L	L	Н
Н	NC	L
L	NC	Н

ELECTRICAL CHARACTERISTICS ($T_A = -40$ °C to 85°C unless otherwise specified)

INPUT

Parameter	Symbol	Test Condition	Min	Тур.*	Max	Unit
Forward Voltage	V_{F}	$I_F = 10 \text{mA}$		1.4	1.8	V
Reverse Voltage	V_R	$I_R = 10 \mu A$	5.0			V
Temperature Coefficient of V _F	$\Delta V_F/\Delta T_A$	$I_F = 10 \text{mA}$		-1.8		mV/°C
Input Capacitance	C_{IN}	$V_F = 0V, f = 1MHz$		60		pF

OUTPUT

Parameter	Symbol	Test Condition	Min	Тур.*	Max	Unit
High Level Supply Current	I_{CCH}	$I_F = 0mA, V_E = 0.5V, V_{CC} = 5.5V$			10	mA
Low Level Supply Current	I_{CCL}	$I_F = 10 \text{mA}, V_{CC} = 5.5 \text{V}$			13	mA
High Level Enable Current	${ m I_{EH}}$	$V_E = 2.0V, V_{CC} = 5.5V$			-1.6	mA
Low Level Enable Current	I_{EL}	$V_E = 0.5V, V_{CC} = 5.5V$			-1.6	mA
High Level Enable Voltage	V_{EH}	$I_F = 10 \text{mA}, V_{CC} = 5.5 \text{V}$	2.0			V
Low Level Enable Voltage	$V_{ ext{EL}}$	$I_F = 10 \text{mA}, V_{CC} = 5.5 \text{V}$			0.8	V

^{*} Typical values at $T_A = 25$ °C



ELECTRICAL CHARACTERISTICS ($T_A = -40$ °C to 85°C unless otherwise specified)

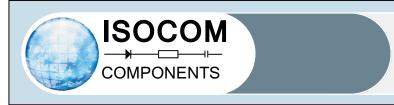
COUPLED

Parameter	Symbol	Test Condition	Min	Тур.*	Max	Unit
High Level Output Current	I_{OH}	$V_{CC} = 5.5V, V_E = 2.0V, V_O = 5.5V, I_F = 250\mu A$			100	μΑ
Low Level Output Voltage	V_{OL}	$V_{CC} = 5.5V, V_E = 2.0V,$ $I_F = 5mA, I_{OL} = 13mA$			0.6	V
Input Threshold Current	I_{FT}	$V_{CC} = 5.5V, V_E = 2.0V,$ $V_O = 0.6V, I_{OL} = 13mA$			5	mA

Switching Characteristics ($T_A = -40$ °C to 85°C, $V_{CC} = 5V$, $I_F = 7.5$ mA unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Тур.*	Max	Unit
Propagation Delay Time to Output High Level	$t_{ m PHL}$	$C_L = 15 pF, R_L = 350\Omega,$ $T_A = 25 °C$		35	75	ns
Propagation Delay Time to Output Low level	t _{PLH}	$C_L = 15 pF, R_L = 350 \Omega,$ $T_A = 25 °C$		45	75	ns
Pulse Width Distortion	t _{PHL} -t _{PLH}	$C_L = 15pF, R_L = 350\Omega$		10	35	ns
Output Rise Time	$t_{\rm r}$	$C_L = 15 pF, R_L = 350\Omega$		30	40	ns
Output Fall Time	t_{f}	$C_{L} = 15 pF, R_{L} = 350 \Omega$		10	20	ns
Enable Propagation Delay Time to Output High Level	t _{ELH}	$I_F = 7.5 \text{mA},$ $V_{EL} = 0 \text{V}, V_{EH} = 3 \text{V},$ $C_L = 15 \text{pF}, R_L = 350 \Omega$		30	40	ns
Enable Propagation Delay Time to Output Low Level	$t_{ m EHL}$			20	30	ns

^{*} Typical values at $T_A = 25$ °C



ELECTRICAL CHARACTERISTICS ($T_A = -40$ °C to 85°C unless otherwise specified)

Switching Characteristics ($T_A = -40^{\circ}\text{C}$ to 85°C, $V_{CC} = 5\text{V}$, $I_F = 7.5\text{mA}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Тур.*	Max	Unit
Common Mode Transient Immunity at Logic High	CM _H	ICPL0600 (Fig 14) $I_{F} = 0 \text{mA}, V_{OH} = 2 \text{V},$ $R_{L} = 350 \Omega, V_{CM} = 10 \text{Vp-p},$ $T_{C} = 25 \Omega$				V/µs
		$T_A = 25$ °C ICPL0601 (Fig 14) $I_F = 0$ mA, $V_{OH} = 2$ V, $R_L = 350\Omega$, $V_{CM} = 50$ Vp-p,	5000			
		$T_A = 25$ °C ICPL0611 (Fig 14) $I_F = 0$ mA, $V_{OH} = 2$ V, $R_L = 350\Omega$, $V_{CM} = 400$ Vp-p, $T_A = 25$ °C	10000			
		ICPL0611 (Fig 15) $I_{F} = 0 \text{mA}, V_{OH} = 2V,$ $R_{L} = 350\Omega, V_{CM} = 400V \text{p-p},$ $T_{A} = 25^{\circ}\text{C}$	15000			
Common Mode Transient Immunity at Logic Low	CM_L	ICPL0600 (Fig 14) $I_{F} = 7.5\text{mA}, V_{OL} = 0.8\text{V},$ $R_{L} = 350\Omega, V_{CM} = 10\text{Vp-p},$ $T_{A} = 25^{\circ}\text{C}$				V/µs
		ICPL0601 (Fig 14) $I_F = 7.5 \text{mA}, V_{OL} = 0.8 \text{V},$ $R_L = 350 \Omega, V_{CM} = 50 \text{Vp-p},$ $T_A = 25^{\circ}\text{C}$	5000			
		ICPL0611 (Fig 14) $I_F = 7.5 \text{mA}, V_{OL} = 0.8 \text{V}, \\ R_L = 350 \Omega, V_{CM} = 400 \text{Vp-p}, \\ T_A = 25^{\circ}\text{C}$	10000			
		ICPL0611 (Fig 15) $I_F = 7.5 \text{mA}, V_{OL} = 0.8 \text{V},$ $R_L = 350 \Omega, V_{CM} = 400 \text{Vp-p},$ $T_A = 25 ^{\circ}\text{C}$	15000			

^{*} Typical values at $T_A = 25$ °C



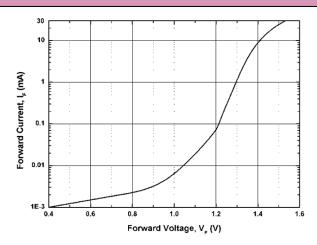


Fig 1 Forward Current vs Forward Voltage

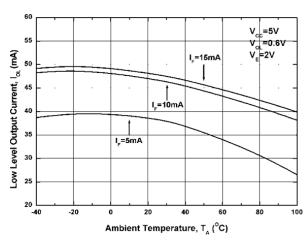


Fig 3 Low Level Output Current vs T_A

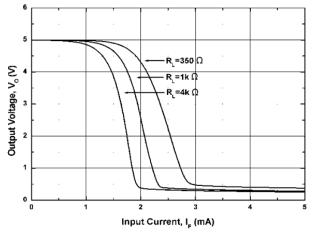


Fig 5 Output Voltage vs Input Forward Current

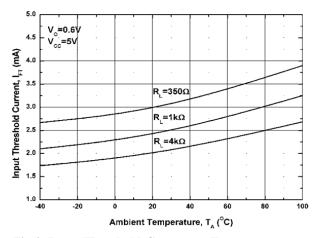


Fig 2 Input Threshold Current vs T_A

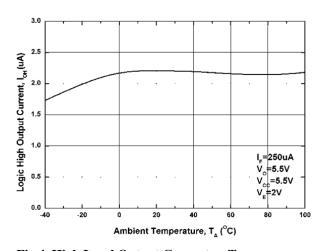


Fig 4 High Level Output Current vs T_A

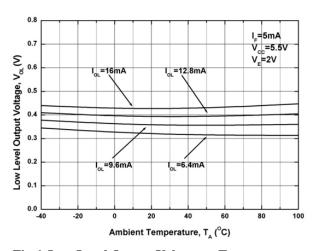


Fig 6 Low Level Output Voltage vs TA



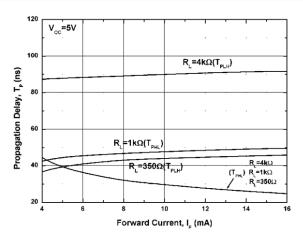


Fig 7 Propagation Delay Time vs Forward Current

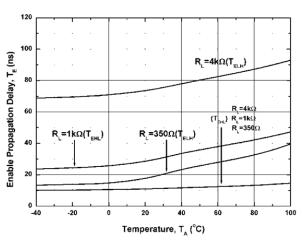


Fig 9 Enable Propagation Delay Time vs T_A

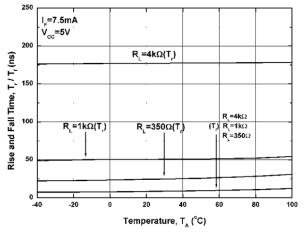


Fig 11 Rise Time / Fall Time vs T_A

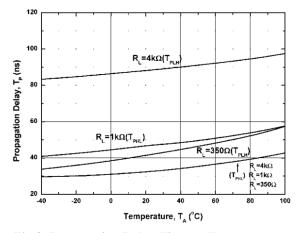


Fig 8 Propagation Delay Time vs T_A

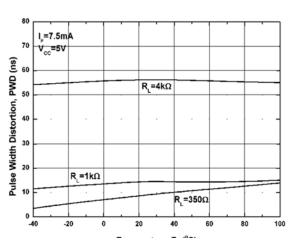
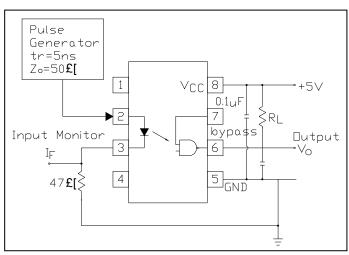


Fig 10 Pulse Width Distortion vs T_A





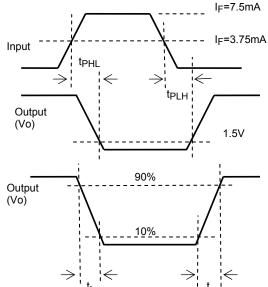


Fig 12 t_{PHL} , t_{PLH} , t_r and t_f Test Circuit

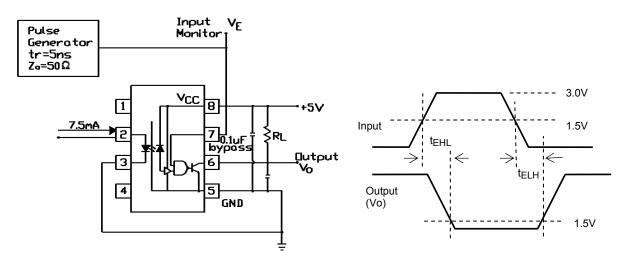


Fig 13 t_{EHL} and t_{ELH} Test Circuit



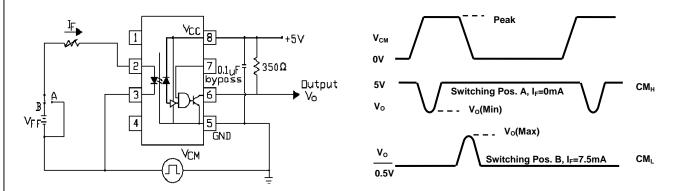


Fig 14 Common Mode Transient Immunity Test Circuit

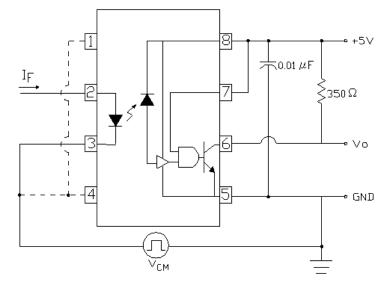
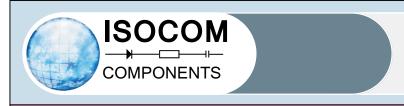


Fig 15 High Common Mode Transient Immunity Test Circuit

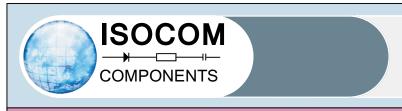
Common mode transient immunity in logic high level is the maximum tolerable (positive) dV_{CM}/dt on the leading edge of the common mode pulse signal V_{CM} , to assure that the output will remain in a logic high state (i.e., $V_O > 2.0V$).

Common mode transient immunity in logic low level is the maximum tolerable (negative) dV_{CM}/dt on the trailing edge of the common mode pulse signal, V_{CM} , to assure that the output will remain in a logic low state (i.e., $V_O < 0.8V$).



Notes:

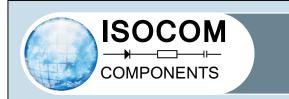
- The V_{CC} supply must be bypassed by a 0.1μF capacitor or larger with good high frequency characteristic and should be connected as close as possible to the package V_{CC} and GND pins.
- Enable Input No pull up resistor required as the device has an internal pull up resistor.
- t_{PLH} is measured from the 3.75mA level on the HIGH to LOW transition of the input current pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
- t_{PHL} is measured from the 3.75mA level on the LOW to HIGH transition of the input current pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- t_r Rise time is measured from the 10% to the 90% levels on the LOW to HIGH transition of the output pulse.
- t_f Fall time is measured from the 90% to the 10% levels on the HIGH to LOW transition of the output pulse.
- t_{ELH} is measured from the 1.5V level on the HIGH to LOW transition of the input Enable voltage pulse to the 1.5V level on the LOW to HIGH transition of the output voltage pulse.
- t_{EHL} is measured from the 1.5V level on the LOW to HIGH transition of the input Enable voltage pulse to the 1.5V level on the HIGH to LOW transition of the output voltage pulse.
- CM_{H} The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the HIGH state (i.e., $V_O > 2.0V$).
- CM_L The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the LOW output state (i.e., $V_O < 0.8V$).



ORDER INFORMATION

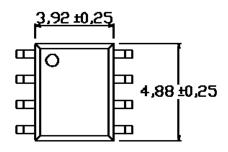
ICPL0600, ICPL0601, ICPL0611

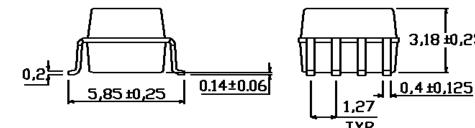
After PN	Description	Packing quantity
None	Surface Mount Tube Packaging	100 pcs per tube
T&R	Surface Mount Tape & Reel	2000 pcs per reel



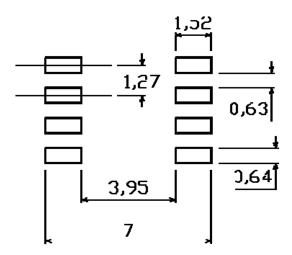
3,18 ±0,25

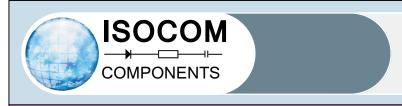
PACKAGE DIMENSIONS (mm)



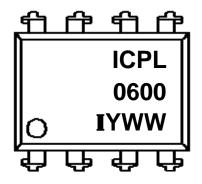


Recommended Solder Pad Layout (mm)





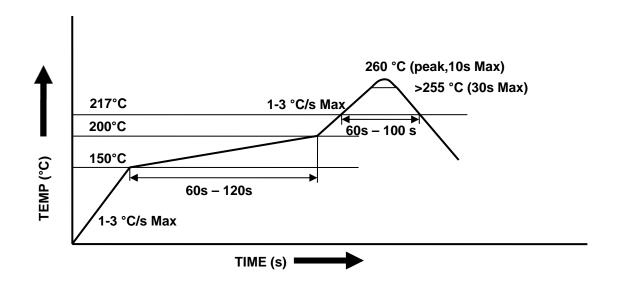
Device Marking (Example ICPL0600)



ICPL0600 denotes Device Part Number Y denotes 1 digit Year code WW denotes 2 digit Week code

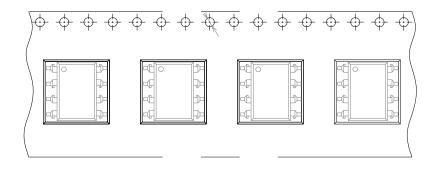
I denotes Isocom

REFLOW SOLDERING TEMPERATURE PROFILE



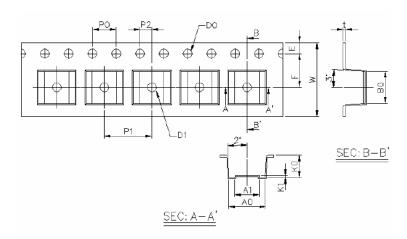


Tape and Reel Packaging





Direction of feed from reel



Dimension No.	Α0	A 1	В0	D0	D1	E	F
Dimension (mm)	6.2±0.1	4.1±0.1	5.28±0.1	1.5±0.1	1.5±0.3	1.75±0.1	5.5±0.1
Dimension No.	Ро	P1	P2	t	w	K0	K1
					12.0		